

NOT RECOMMENDED FOR NEW DESIGN **CONTACT US**



DMN5L06K

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)}	I _D T _A = +25°C
50V	2.0Ω @ V _{GS} = 5.0V	300mA
	2.5Ω @ V _{GS} = 2.5V	200mA

Features and Benefits

- Low On-Resistance
- Very Low Gate Threshold Voltage (1.0V Max)
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected up to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High-Reliability.

https://www.diodes.com/quality/product-definitions/

An Automotive-Compliant Part is Available Under Separate Datasheet (DMN5L06KQ)

Description and Applications

This new generation 50V N-channel enhancement mode MOSFET is designed to minimize RDS(ON) yet maintain superior switching performance. This device is ideal for use in notebook battery power management and load switches.

- Load switches
- Level switches

Mechanical Data

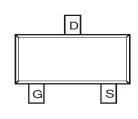
- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Annealed over Alloy 42 Lead-Frame. Solderable per MIL-STD-202, Method 208 @3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (Approximate)







Equivalent Circuit



View

Top View

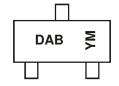
Ordering Information (Note 4)

Part Number	Dockers	Packing			
Part Number	Package	Qty.	Carrier		
DMN5L06K-7	SOT23	3000	Tape & Reel		

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.</p>
 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



DAB = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: J = 2022) M = Month (ex: 9 = September)

Date Code Kev

Date Code Hoj												
Year	2006		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	T		J	K	L	М	N	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain Source Voltage	V _{DSS}	50	V
Gate-Source Voltage	Vgss	±20	V
Drain Current (Note 5) Continuous Pulsed (Note 6)	lo	300 800	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	350	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta JA}$	357	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-65 to +150	°C

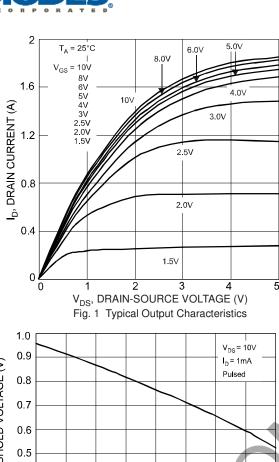
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	,					
Drain-Source Breakdown Voltage	BVDSS	50			>	$V_{GS} = 0V$, $I_D = 10\mu A$
Zero Gate Voltage Drain Current @ $T_C = +25$ °C	IDSS	1		60	nA	$V_{DS}=50V,\ V_{GS}=0V$
Gate-Body Leakage	lgss	_	-/	1 500 50	μΑ nA nA	$V_{GS} = \pm 12V, V_{DS} = 0V$ $V_{GS} = \pm 10V, V_{DS} = 0V$ $V_{GS} = \pm 5V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	0.49		1.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
Static Drain-Source On-Resistance	R _{DS(ON)}	_ _ _	2.71 1.56 1.19	3.0 2.5 2.0	Ω	$V_{GS} = 1.8V, I_{D} = 50mA$ $V_{GS} = 2.5V, I_{D} = 50mA$ $V_{GS} = 5.0V, I_{D} = 50mA$
On-State Drain Current	ID(ON)	0.5	1.4	_	Α	Vgs = 10V, Vps = 7.5V
Forward Transconductance	Y _{fs}	200	_	_	mS	$V_{DS} = 10V, I_D = 0.2A$
Source-Drain Diode Forward Voltage	V _{SD}	0.5	0.7	1.4	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	_	50	pF	
Output Capacitance			_	25	pF	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	_	5.0	pF	1 – 1.0IVII IZ

Notes:

- 5. Device mounted on FR-4 PCB.
 6. Pulse width ≤ 10ms, duty cycle ≤ 1%.
 7. Short duration pulse test used to minimize self-heating effect.
 8. Guaranteed by design. Not subject to product testing.





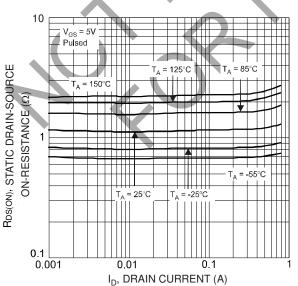
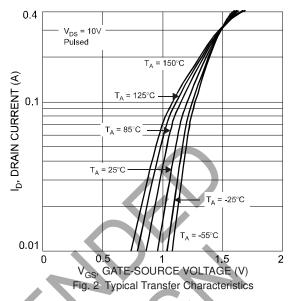


Fig. 5 Static Drain-Source On-Resistance vs. Drain Current



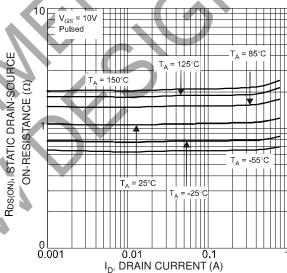


Fig. 4 Static Drain-Source On-Resistance vs. Drain Current

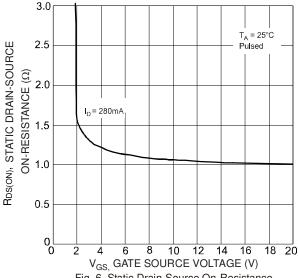


Fig. 6 Static Drain-Source On-Resistance vs. Gate-Source Voltage



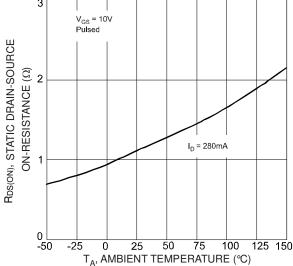
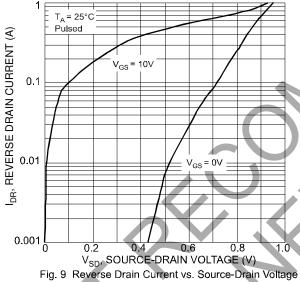
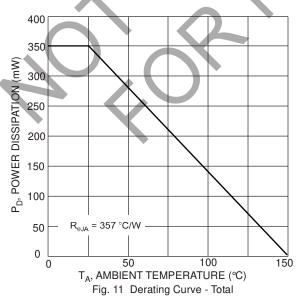
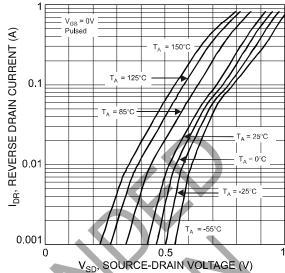


Fig. 7 Static Drain-Source On-State Resistance vs. Ambient Temperature







8 Reverse Drain Current vs. Source-Drain Voltage

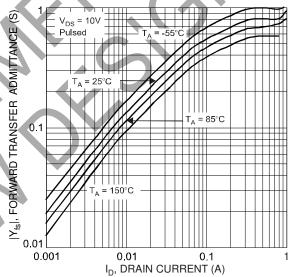
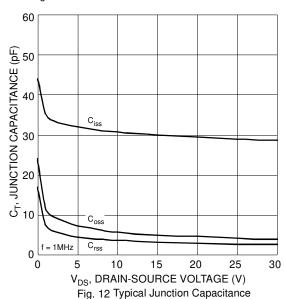


Fig. 10 Forward Transfer Admittance vs. Drain Current

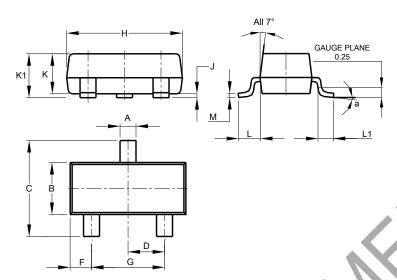




Package Outline Dimensions

 $Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

SOT23

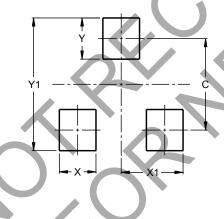


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
O	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Ŧ	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
F	0.45	0.61	0.55				
<u>L</u>	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
X	0.8
X1	1.35
Υ	0.9
Y1	2.9



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